



T12M35T600B(LS)

Triacs Silicon Bidirectional Thyristors

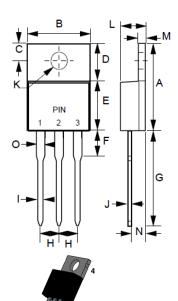
TRIACS 12 AMPERES RMS 600 VOLTS

FEATURES

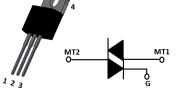
- Blocking voltage to 600V
- High immunity to dv/dt 400V/us Minimum at +125°C
- High Surge Current of 100 Amperes
- Uniform Gate Trigger Currents in Three Quadrants, Q1, Q2, and Q3
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

MECHANICAL DATA

- Package: TO-220AB
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202. Method 208 @3
- Weight: 0.07 ounces, 2.0 grams (Approximate)



TO-220AB				
	TO-220AB			
-	DIM.	MIN.	MAX	
<u>⊸</u> M	Α	14.22	15.88	
- ♠	В	9.65	10.67	
_†	С	2.54	3.43	
$H \mid_{\mathbf{A}}$	D	5.84	6.86	
	E	8.26	9.28	
	F		6.35	
₩	G	12.70	14.73	
⊣	Н	2.29	2.79	
	ı	0.51	1.14	
	J	0.40	0.67	
G	K	3.53Ø	4.09Ø	
	L	3.56	4.83	
•	M	1.14	1.40	
♦	N	2.03	2.92	
1	0	1.17	1.37	
1	All Dimensions in millimeter.			



PIN ASSIGNMENT		
1	Main terminal 1	
2	Main terminal 2	
3	Gate	
4	Main terminal 2	

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at +25°C ambient temperature unless otherwise specified.

MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Peak repetitive off-state voltage (T _J = -40 to +110°C, sine wave, 50 to 60Hz; gate open)	V _{DRM} V _{RRM}	600 600	Volts
On-stage RMS current (full sine wave 50 to 60Hz, $T_C = +70$ °C)	I _{T(RMS)}	12	Amp
Peak non-repetitive surge current (one full cycle 60Hz, T _J = +25°C)	I _{TSM}	100	Amps
Circuit fusing consideration (t = 8.3ms)	l²t	41	A ² s
Operating junction temperature range	TJ	-40 to +125	°C
Storage temperature range	T _{STG}	-40 to +150	°C

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Blocking, voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.



OFF CHARACTERISTICS

PARAMETER		SYMBOL	MAX	UNIT
Peak repetitive forward or reverse blocking current	$T_J = +25$ °C	I_{DRM}	0.01	mΛ
$(V_{AK} = rated V_{DRM} and V_{RRM}, gate open)$	$T_J = +125^{\circ}C$	I _{RRM}	2.0	mA

ON CHARACTERISTICS

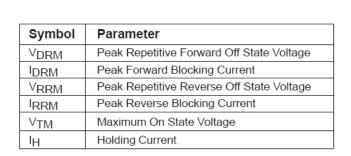
PARAMETER	SYMBOL	MAX	UNIT
Peak forward on-state voltage (I _{TM} = ±12A @ t _P ≤ 2.0ms, duty cycle ≤ 2%)	V _{TM}	1.85	Volts
Gate trigger current $(V_D = 12V, R_L = 100\Omega)$	I _{GT1} I _{GT2} I _{GT3}	35 35 35	mA
Gate trigger voltage $(V_D = 12V, R_L = 100\Omega)$	V _{GT1} V _{GT2} V _{GT3}	1.5 1.5 1.5	Volts
Holding current (V _D = 12V, initiation current = ±150mA, gate open)	Ін	40	mA
Latching current (V _D = 12V, I _G = 35mA)	I _{L1} I _{L2} I _{L3}	50 80 50	mA

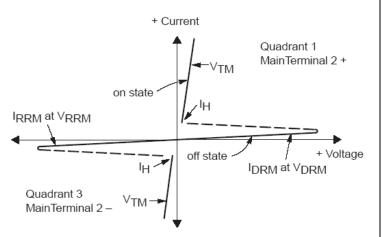
DYNAMIC CHARACTERISTICS

PARAMETER	SYMBOL	MIN	UNIT
Critical rate of rise of Commutation voltage $V_D = 67\%$ rated V_{DRM} , exponential waveform, gate open, $T_J = +125$ °C	dv/dt	400	V/µs

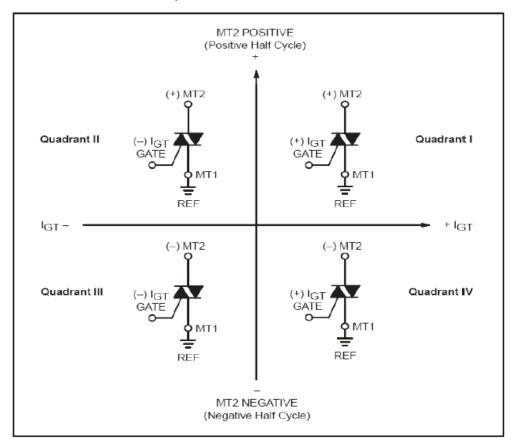


RATING AND CHARACTERISTIC CURVES T12M35T600B(LS)





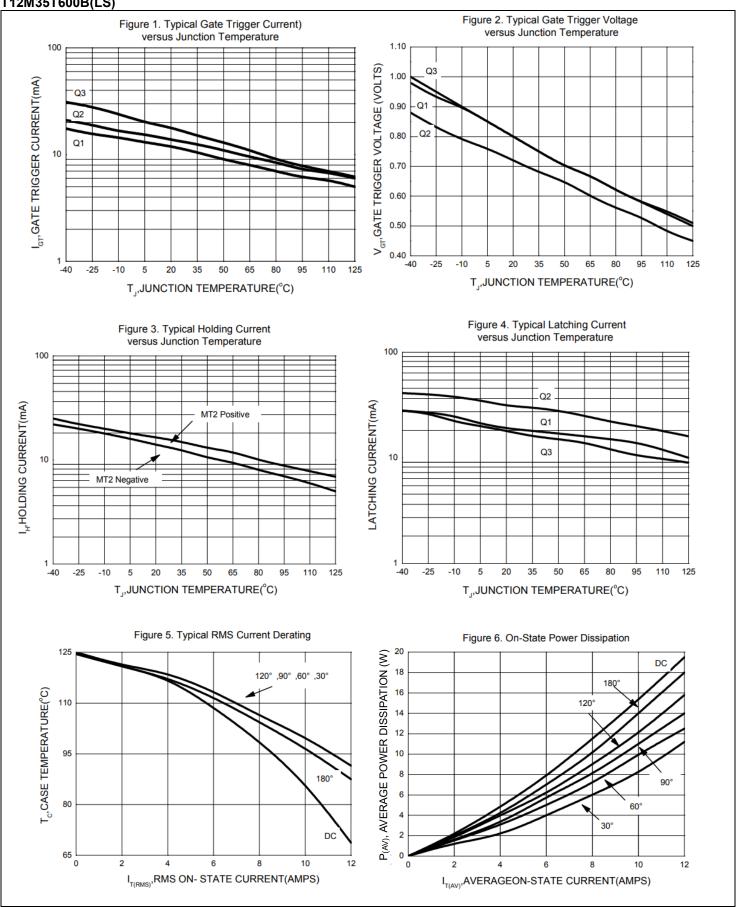
Quadrant Definitions



All polarities are referenced to MT1 Whith in -phase signal (using standard AC lines) quadrants I and III are used

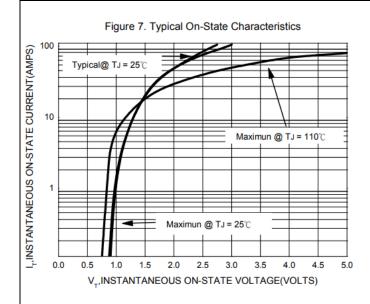


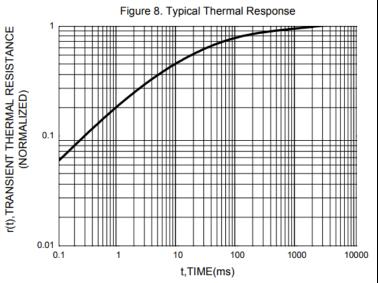
RATING AND CHARACTERISTIC CURVES T12M35T600B(LS)





RATING AND CHARACTERISTIC CURVES T12M35T600B(LS)



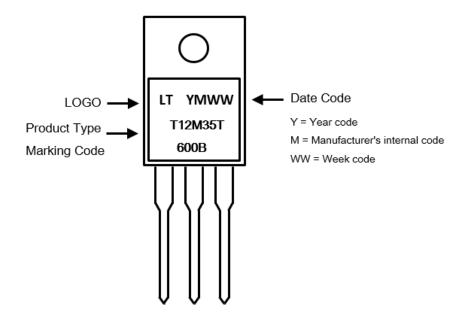




Ordering Information:

Part Number	Packago	Packing		
	Package	Qty.	Carrier	
T12M35T600B	TO-220AB	50pcs	Tube	

Marking Information:





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